

# **80V N-Channel Trench MOSFET**

#### **Features**

- Trench Power Technology
- Low R<sub>DS(ON)</sub>
- Low Gate Charge
- Optimized for Fast-switching Applications

#### **Applications**

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial

#### **Product Summary**

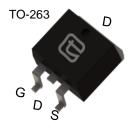
V<sub>DS</sub> 80V

 $R_{DS(ON)}$  (at  $V_{GS}=10V$ ) <  $6m\Omega$ 

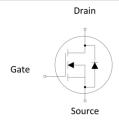
 $I_D$  (at  $V_{GS}$ =10V) 120A

100% UIS Tested









Device	Package	Marking
TMB120N08A	TO-263	120N08A
TMP120N08A	TO-220	120N08A

Absolute Maximum Ratings $I_C = 25^{\circ}$ C, unless otherwise noted					
Parameter		Symbol	Value	Unit	
Drain-Source Voltage (V <sub>GS</sub> = 0V)			V <sub>DSS</sub>	80	V
Ozationa Posic Orașest	$T_{\rm C} = 25^{\rm o}{\rm C}$			120	А
Continuous Drain Current	$T_{\rm C} = 100^{\rm o}{\rm C}$		I <sub>D</sub>	84	
Pulsed Drain Current (note1)		(note1)	I <sub>DM</sub>	480	Α
Gate-Source Voltage		$V_{\rm GSS}$	±20	V	
Single Pulse Avalanche Energy (note2)		E <sub>AS</sub>	540	mJ	
Avalanche Current		I <sub>As</sub>	60	Α	
Power Dissipation (note3)	$T_{\rm C} = 25^{\circ}{\rm C}$		P <sub>D</sub>	208	W
	$T_{\rm C} = 100^{\circ}{\rm C}$			104	W
Operating Junction and Storage Temperature Range		Tı, T <sub>eta</sub>	-55~+175	°C	

Thermal Resistance			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	0.72	00/4/
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62.5	°C/W



Specifications T <sub>J</sub> = 25°C, unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static				1,76.		
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_{D} = 250\mu A$	80			V
		$V_{DS} = 80V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 80V, V_{GS} = 0V, T_{J} = 100^{\circ}C$			25	μA
Gate-Source Leakage	I <sub>GSS</sub>	$V_{GS} = \pm 20V$			±100	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 30A$		4.6	6.0	mΩ
Forward Transconductance	9 <sub>fs</sub>	$V_{DS} = 5V, I_{D} = 20A$	40			S
Dynamic	•		•	•	•	
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V,		5400		pF
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 40V$ ,		390		
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		260		
Total Gate Charge	Q <sub>g</sub>			130		
Gate-Source Charge	$Q_{gs}$	$V_{DD} = 40V, I_{D} = 20A, V_{GS} = 10V$		24		nC
Gate-Drain Charge	$Q_{gd}$	. 63		49		
Turn-on Delay Time	t <sub>d(on)</sub>	$V_{DD} = 40V, I_D = 2A,$ $R_G = 2.5\Omega$		28		
Turn-on Rise Time	t <sub>r</sub>			29.5		
Turn-off Delay Time	t <sub>d(off)</sub>			41		ns
Turn-off Fall Time	t <sub>f</sub>			15.6		
Drain-Source Body Diode Characte	eristics					
Continuous Body Diode Current	Is	T <sub>C</sub> = 25°C			120	۸
Pulsed Diode Forward Current	I <sub>SM</sub>				480	Α
Body Diode Voltage	V <sub>SD</sub>	$T_J = 25^{\circ}C$ , $I_{SD} = 20A$ , $V_{GS} = 0V$			1.2	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 20A,		45		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt = 500A/µs		54		nC

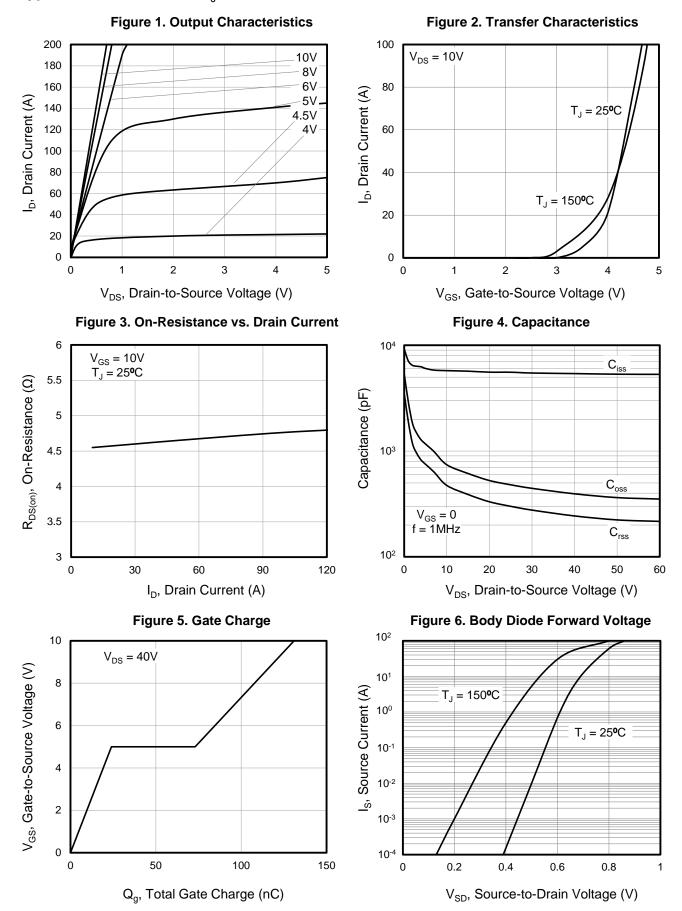
#### **Notes**

- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2.  $I_{AS} = 60A$ ,  $V_{DD} = 50V$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^{\circ}C$
- 3. The power dissipation PD is based on  $TJ(MAX)=175^{\circ}$  C, using junction-to-case thermal resistance.

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### **Typical Characteristics** $T_J = 25^{\circ}\text{C}$ , unless otherwise noted





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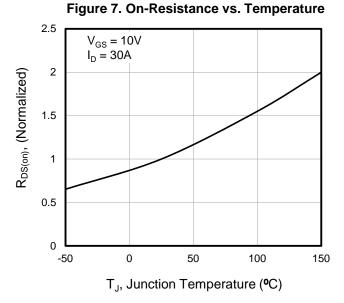
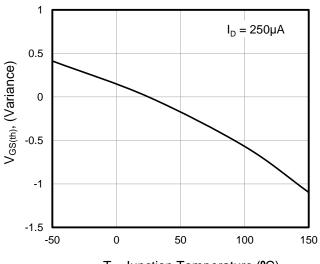


Figure 8. Threshold Voltage vs. Temperature



T<sub>J</sub>, Junction Temperature (°C)

Figure 9. Transient Thermal Impedance

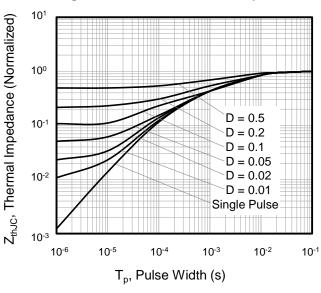


Figure 10. Safe operation area

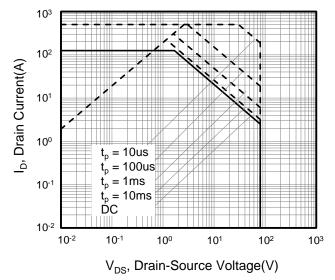




Figure A: Gate Charge Test Circuit and Waveform

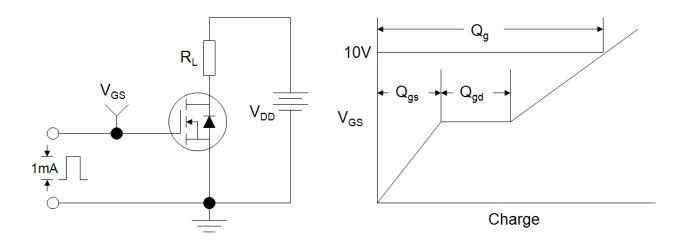


Figure B: Resistive Switching Test Circuit and Waveform

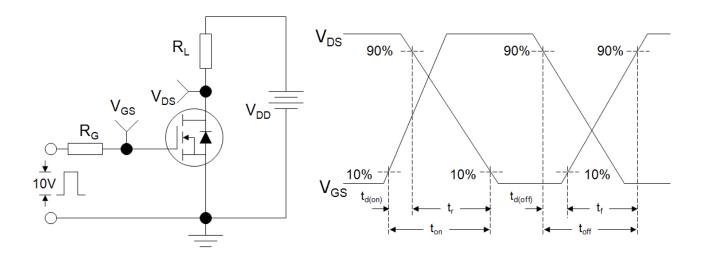
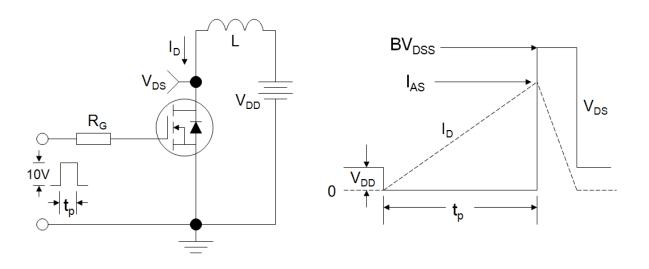


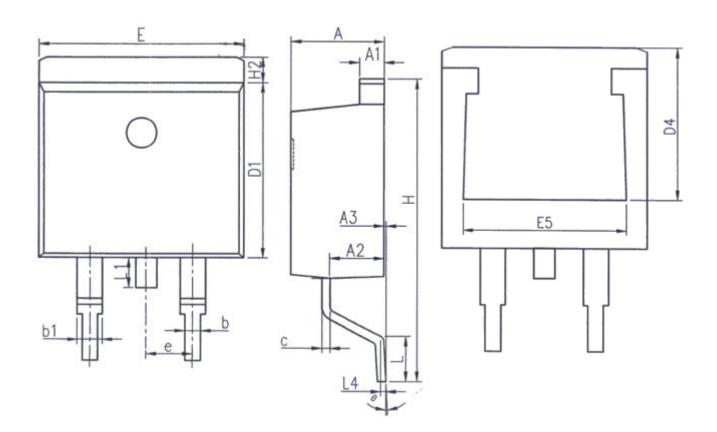
Figure C: Unclamped Inductive Switching Test Circuit and Waveform



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# **TO-263**

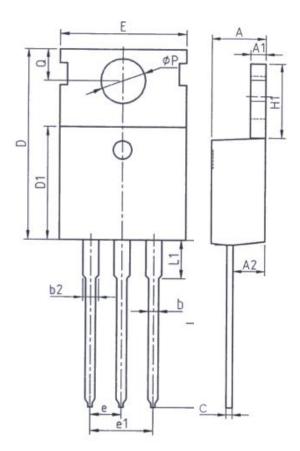


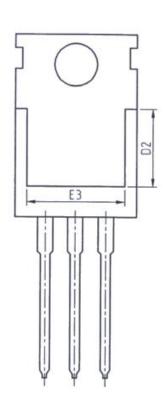
Unit: mm			
Symbol	Min.	Max.	
Α	4. 37	4. 77	
<b>A</b> 1	1. 22	1. 42	
A2	2. 49	2. 89	
A3	0. 00	0. 25	
b	0. 70	0. 96	
b1	1. 17	1. 47	
С	0. 30	0. 53	
D1	8. 50	8. 90	
D4	6. 60	_	

Unit: mm			
Symbol	Min.	Max.	
E	9.86	10.36	
<b>E</b> 5	7. 06	-	
е	2. 54BSC		
Н	14. 70	15. 50	
H2	1. 07	1. 47	
L	2.00	2. 60	
L1	1. 40	1. 70	
L4	0. 25BSC		
θ	0°	9°	



# **TO-220**





Unit: mm		
Symbol	Min.	Max.
Α	4. 37	4. 77
A1	1. 25	1. 45
A2	2. 20	2. 60
b	0. 70	0. 95
b2	1. 17	1. 47
С	0. 40	0. 65
D	15. 10	16. 10
D1	8. 80	9. 40
D2	5. 50	_

Unit: mm			
Symbol	Min. Max.		
E	9. 70	10. 30	
E3	7. 00	-	
е	2. 54BSC		
e1	5. 08BSC		
H1	6. 25	6. 85	
L	12. 75	13.80	
L1	- 3.4		
Р	3. 40	3. 80	
Q	2. 60	3. 00	



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